Bipolar Transistor





Description:



A Silicon NPN transistor in a TO-39 case intended for high speed switching applications.

Absolute Maximum Ratings:

Collector-Base Voltage, VCBO	: 75V
Collector-Emitter Voltage, VCEO	: 40V
Emitter-Base Voltage, VEBO	: 6V
Continuous Collector Current, Ic	: 800mA
Total Device Dissipation (Tc = +25°C), PD	: 1.2W
Derate above 25°C	: 6.85mW/ºC
Total Device Dissipation (TA = + 25°C), PD	: 400mW
Derate above 25°C	: 2.28mW/ºC
Operating Junction Temperature Range, TJ	: -65°C to +200 °C
Storage Temperature Range, T _{stg}	: -65°C to 200°C

Electrical Characteristics: (T_A = +25°C Unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Max	Unit
OFF Characteristics					
Collector-Emitter Breakdown Voltage	V(br)ceo	Ic = 10mA, I _B = 0	40	-	V
Collector-Base Breakdown Voltage	V(br)cbo	Ic = 10μA, Iε = 0	75	-	V
Emitter-Base Breakdown Voltage	V(br)ebo	IE = 10μA, IC = 0	6	-	V
Collector Cut-Off Current	Ісво	Vce = 60V, Ie = 0	-	0.01	μA
		Vce = 60V, Ie = 0, TA = +150°C	-	10	μA
	ICEX	Vce = 60V, Veb _(off) = 3V	-	10	μA
Emitter Cut-Off Current	Іево	VEB = 3V, IC = 0	-	10	μA
Base Cut-Off Current	IBL	Vce = 60V, Veb _(off) = 0	-	20	μA
On Characteristics	,		1		
DC Curent Gain	hfe	Ic = 0.1mA, VcE = 10V	20	-	-
		Ic = 1mA, Vce = 10V	25	-	-
		Ic = 10mA, Vce = 10V	35	-	-
		Ic = 10mA, Vce = 10V, TA = -55°C	15	-	-
		Ic = 150mA, Vce = 10V (Note 1)	40	120	-
		Ic = 150mA, Vce = 1V (Note 1)	20	-	-
		Ic = 500mA, Vce = 10V (Note 1)	25	-	-
Collector-Emitter Saturation Voltage	VCE(sat)	Ic = 150mA, Iв = 5mA	-	0.3	V
(Note 1)		Ic = 500mA, Iв = 50mA	-	1	V
Base-Emitter Saturation Voltage	VBE(sat)	Ic = 150mA, Iв = 15mA	0.6	1.2	V
(Note 1)		Ic = 500mA, Iв = 50mA	-	2	V

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Small-Signal Characteristics

Current Gain-Bandwidth Product (Note 2)	f⊤	Ic = 20mA, Vce = 20V, f = 100MHz, (Note 2)		-	MHz
Output Capacitance	Cobo	Vсв = 10V, IE = 0, f = 100kHz		8	pF
Input Capacitance	Cibo	VEB = 0.5V, Ic = 0, f = 10kHz		25	pF
Input Impedance	h _{ie}	Ic = 1mA, Vce = 10V, f = 1kHz	1	3.5	kΩ
		Ic = 10mA, Vce = 10V, f = 1kHz	0.2	1	kΩ
Voltage Feedback Ratio	H _{re}	Ic = 1mA, Vce = 10V, f = 1kHz		5	×10 ⁴
		Ic = 10mA, Vce = 10V, f = 1kHz	-	2.5	×10 ⁴
Output Admittance	hoe	Ic = 1mA, Vce = 10V, f = 1kHz	3	15	µmhos
		Ic = 10mA, Vce = 10V, f = 1kHz	10	100	µmhos
Collector-Base Time Constant	rb'Cc	Ic = 20mA, Vcв = 20V, f = 31.8MHz	5	150	ps
Noise Figure	NF	Ic = 100μA, Vce = 10V, Rs = 1κΩ, f = 1kMHz		4	dB
Real Part of Common-Emitter High Frequency input Impedance	Re(hie)	Ic = 20mA, Vce = 20V, f = 300MHz		60	Ω

Switching Characteristics

Delay Time	tq	Vcc = 30V, Ic = 150mA, Vce(off) = 0.5V, IB1 = 15mA		10	ns
Rise Time	tr			25	ns
Storage Time	ts Vcc = 30V, Ic = 150mA, IB1 = IB2 = 15mA		-	225	ns
Fall Time	tr	VCC - 30V, IC - 130IIIA, IB1 - IB2 - 13IIIA		60	ns
Active Region Time Constant	TA	Ic = 150mA, Vce = 30V	-	2.5	ns

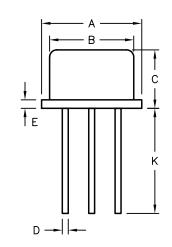
Notes

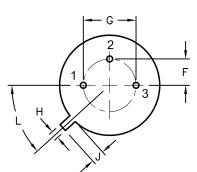
1. Pulse Test: Pulse Width \leq 300s, Duty Cycle \leq 2%.

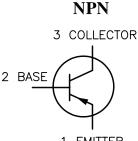
2. ft is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.







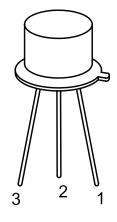




1 EMITTER

Dim	Min	Мах
A	8.5	9.39
В	7.74	8.5
С	6.09	6.6
D	0.4	0.53
E	-	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.83
J	0.73	0.86
К	12.7	-
L	42°	48°

STYLE 1 PIN 1. EMITTER 2. BASE 3. COLLECTOR



Dimensions : Millimetres

Part Number Table

Description	Part Number			
Bipolar Transistor	2N2218A			

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